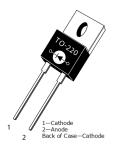


## MSC020SDA120K Zero Recovery Silicon Carbide Schottky Diode

#### **Product Overview**

The silicon carbide (SiC) power Schottky barrier diode (SBD) product line from Microsemi increases the performance over silicon diode solutions while lowering the total cost of ownership for high-voltage applications. MSC020SDA120K is a 1200 V, 20 A SiC SBD in a two-lead TO-220 package.



#### **Features**

The following are key features of the MSC020SDA120K device:

- No reverse recovery
- · Low forward voltage
- · Low leakage current
- Avalanche-energy rated
- RoHS compliant

#### **Benefits**

The following are benefits of the MSC020SDA120K device:

- · High switching frequency
- Low switching losses
- Low noise (EMI) switching
- Higher reliability systems
- Increased system power density

#### **Applications**

The MSC020SDA120K device is designed for the following applications:

- Power factor correction (PFC)
- Anti-parallel diode
  - Switch-mode power supply
  - Inverters/converters
  - Motor controllers
- · Freewheeling diode
  - Switch-mode power supply
  - Inverters/converters
- · Snubber/clamp diode



# **Device Specifications**

This section shows the specifications of the MSC020SDA120K device.

### **Absolute Maximum Ratings**

The following table shows the absolute maximum ratings for the MSC020SDA120K device.  $T_C = 25$  °C unless otherwise specified.

**Table 1 • Absolute Maximum Ratings** 

Symbol	Parameter		Ratings	Unit	
V <sub>R</sub>	Maximum DC reverse voltage		1200	V	
V <sub>RRM</sub>	Maximum peak repetitive reverse voltage		1200		
V <sub>RWM</sub>	Maximum working peak reverse voltage		1200		
I <sub>F</sub>	Maximum DC forward current	T <sub>C</sub> = 25 °C	49	А	
		T <sub>C</sub> = 135 °C	22		
		T <sub>C</sub> = 145 °C	18		
I <sub>FRM</sub>	Repetitive peak forward surge current ( $T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave)		64		
I <sub>FSM</sub>	Non-repetitive forward surge current ( $T_C = 25$ °C, $t_p = 8.3$ ms, half sine wave)		115		
P <sub>TOT</sub>	Power dissipation T <sub>0</sub>	T <sub>C</sub> = 25 °C	186	W	
		T <sub>C</sub> = 110 °C	80		
E <sub>AS</sub>	Single pulse avalanche energy (starting $T_J$ = 25 °C, peak $I_L$ = 20 A)		100	mJ	



The following table shows the thermal and mechanical characteristics of the MSC020SDA120K device.

**Table 2 • Thermal and Mechanical Characteristics** 

Symbol	Characteristic/Test Conditions	Min	Тур	Max	Unit
R <sub>ÐJC</sub>	Junction-to-case thermal resistance		0.65	0.95	°C/W
T <sub>J</sub> , T <sub>STG</sub>	Operating junction and storage temperature range	<b>-</b> 55		175	°C
T <sub>L</sub>	Lead temperature for 10 seconds		300		°C
Wt	Package weight		0.07		OZ
			1.9		g
	Mounting torque, 6-32 or M3 screw			10	lbf-in
				1.1	N-m

### **Electrical Performance**

The following table shows the static characteristics of the MSC020SDA120K device.  $T_J$  = 25 °C unless otherwise specified.

**Table 3 • Static Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit	
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 20 A		1.5	1.8	V	
		I <sub>F</sub> = 20 A, T <sub>J</sub> = 175 °C		2.1			
I <sub>RM</sub>	Reverse leakage current	V <sub>R</sub> = 1200 V		6	200	μΑ	
		V <sub>R</sub> = 1200 V, T <sub>J</sub> = 175 °C		100			
$Q_C$	Total capacitive charge	V <sub>R</sub> = 600 V		91		nC	
C <sub>J</sub>	Junction capacitance	V <sub>R</sub> = 1 V, f = 1 MHz		1130		pF	
	Junction capacitance	V <sub>R</sub> = 400 V, f = 1 MHz		91			
	Junction capacitance	V <sub>R</sub> = 800 V, f = 1 MHz		74			



### **Typical Performance Curves**

This section shows the typical performance curves of the MSC020SDA120K device.

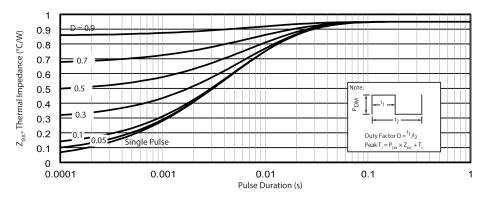


Figure 1 • Maximum Transient Thermal Impedance

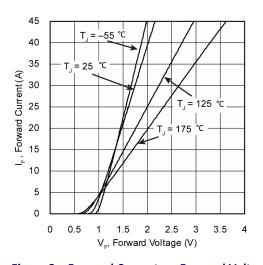


Figure 2 • Forward Current vs. Forward Voltage

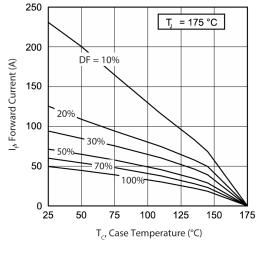


Figure 3 • Max. Forward Current vs. Case Temp.

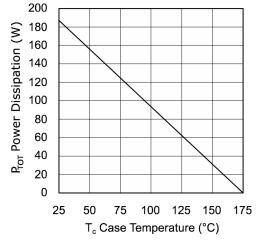


Figure 4 • Max. Power Dissipation vs. Case Temp.

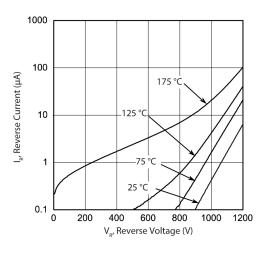


Figure 5 • Reverse Current vs. Reverse Voltage



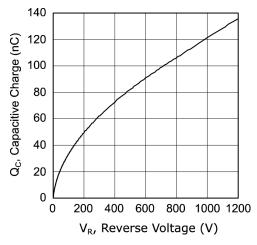


Figure 6 • Total Charge vs. Reverse Voltage

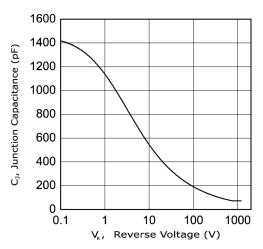


Figure 7 • Capacitance vs. Reverse Voltage



# **Package Specification**

This section shows the package specification of the MSC020SDA120K device.

### **Package Outline Drawing**

The following figure illustrates the TO-220 package outline of the MSC020SDA120K device.

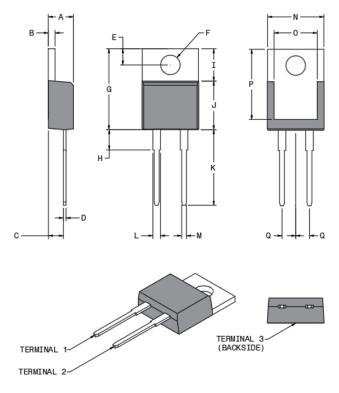


Figure 8 • Package Outline Drawing

The following table shows the TO-220 dimensions and should be used in conjunction with the package outline drawing.

Table 4 • TO-220 Dimensions

Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)
А	4.32	4.57	0.170	0.180
В	1.14	1.40	0.045	0.055
С	2.50	2.74	0.098	0.108
D	0.36	0.53	0.014	0.021
Е	2.65	3.05	0.104	0.120
F	3.60	3.96	0.142	0.156



Symbol	Min (mm)	Max (mm)	Min (in.)	Max (in.)	
G	14.50	15.60	0.571	0.614	
Н	2.39	3.65	0.094	0.144	
1	6.00	6.80	0.236	0.268	
J	8.40	9.00	0.331	0.354	
К	13.00	14.00	0.512	0.051	
L	1.23	1.39	0.048	0.055	
М	0.69	0.88	0.027	0.035	
N	10.00	10.36	0.394	0.408	
0	7.57	7.90	0.298	0.311	
Р	12.20	13.10	0.480	0.516	
Q	2.54 BSC (nom.)		0.100 BSC (nom.)	<u>'</u>	
Terminal 1	Cathode				
Terminal 2	Anode				
Terminal 3	Cathode				





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